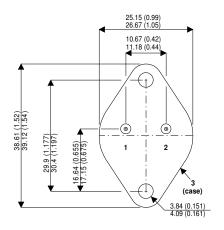
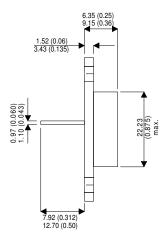


BUV42

MECHANICAL DATA

Dimensions in mm (inches)





Bipolar NPN Device in a Hermetically Sealed TO3 Metal Package

FEATURES

- Low V_{CE(sat)}
- Fast Switching
- Low On-State Voltage Drop

APPLICATIONS

Power Switching Circuits.

TO3 (TO204AA)

Pin 1 = Base Pin 2 = Emitter Case = Collector

ABSOLUTE MAXIMUM RATINGS

| T _{CASE} = 25 °C unless otherwise stated | | | | |
|---|---|--------------|--|--|
| V _{CEX} | Collector - Emitter Voltage ($V_{BE} = -1.5V$) | 350V | | |
| $V_{\sf CEO}$ | Collector - Emitter Voltage | 250V | | |
| V_{EBO} | Emitter – Base Voltage | 7V | | |
| I_{C} | Continuous Collector Current | 12A | | |
| I_{B} | Base Current | 2.5A | | |
| P_{tot} | Total Power Dissipation at T _{case} = 25 ℃ | 120W | | |
| T_{stg} | Storage Temperature | -65 to 200 ℃ | | |

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BUV42

| THERM | AL CHARACTERISTICS | Max. | Unit |
|------------------------|----------------------------|------|------|
| R _{th} j-case | Thermal resistance to case | 1.46 | °C/W |

ELECTRICAL CHARACTERISTICS (T_{case}=25 °C unless otherwise stated)

| | Parameter | Test Conditions | | Min. | Тур. | Max. | Unit |
|------------------------|--|------------------------|------------------------|------|------|------|------|
| I _{CER} | Collector Cutoff Current | V _{CE} = 400V | $R_{BE} = 10\Omega$ | | | 0.5 | |
| | | | T _j = 100 ℃ | | | 2.5 | |
| I _{CEV} | Collector Cut-Off Current | V _{CE} = 400V | $V_{BE} = -1.5V$ | | | 0.5 | mA |
| | | | T _j = 100 ℃ | | | 2 | |
| I _{EBO} | Emitter Cut-Off Current | V _{EB} = 5V | I _C = 0 | | | 1 | |
| V _{(BR)CEO} * | Collector to Emitter Breakdown Voltage | I _C = 0.2A | L = 25mH | 250 | | | |
| $V_{(BR)EBO}$ | Emitter to Base Breakdown Voltage | $I_E = 50 \text{mA}$ | $I_C = 0$ | 7 | | | |
| V _{CE(sat)} * | Collector to Emitter Saturation Voltage | I _C = 4A | $I_B = 0.4A$ | | | 0.9 | V |
| | | | T _j = 100 ℃ | | | 1.2 | - |
| V _{BE(sat)} * | Base to Emitter Saturation Voltage | I _C = 4A | $I_B = 0.4A$ | | | 1.3 | |
| | | | T _j = 100 ℃ | | | 1.3 | |

DYNAMIC CHARACTERISTICS (T_{case}=25 °C unless otherwise stated)

| C_obo | Output Capacitance | $I_E = 0A$ | $V_{CB} = 10V$ | 170 | рF |
|----------------|---------------------|--|--------------------|-----|----|
| Oobo | Output Capacitarice | f = 1.0MHz | | 170 | Pi |
| t _r | Rise Time | V _{CC} = 200V | I _C =6A | 0.4 | |
| t _s | Storage Time | I _{B1} =-I _{B2} =0.75A | | 1.6 | μs |
| t _f | Fall Time | | | 0.3 | |

^{*} Pulse test t_p = 300 μ s, δ < 2%

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